

Features :

- 650V Schottky Diode
- Zero Reverse Recovery Current
- High Frequency Operation
- Positive Temperature Coefficient
- Temperature independent Switching

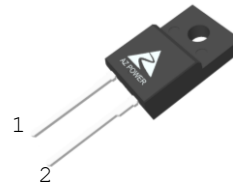
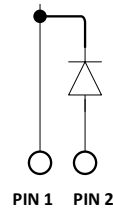
Benefits :

- Unipolar Rectifier
- Minimal switching loss
- Higher Efficiency
- Low cooling requirement

Symbol	Value	Unit
V_{RRM}	650	V
$I_F (T_C=125^\circ C)$	10	A
Q_C	38	nC

Applications :

- Switch Mode Power Supply
- Booster diodes in PFC, DC/DC
- AC/DC converters

Outline

TO-220-2F
P
Circuit

Maximum Ratings

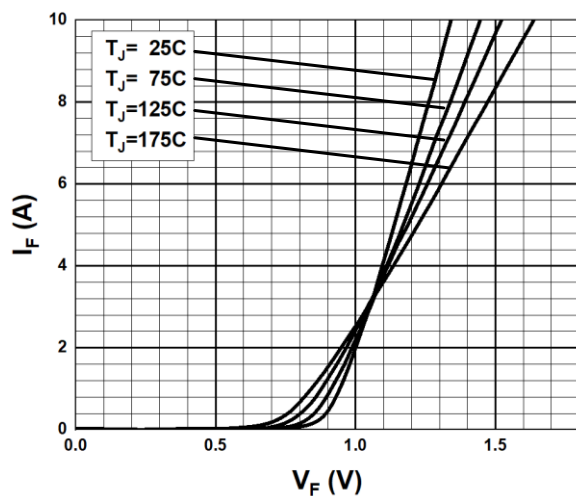
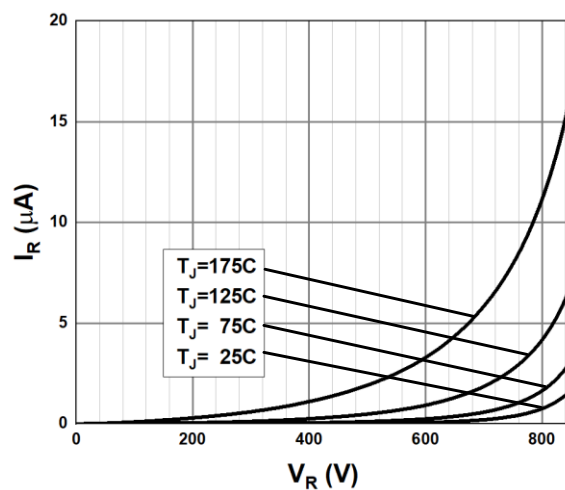
Symbol	Parameter	Value	Unit	Test Conditions
V_R	DC Peak Reverse Voltage	650	V	$T_J = 25^\circ C$
V_{RRM}	Repetitive Peak Reverse	650	V	$T_J = 25^\circ C$
V_{RSM}	Surge Peak Reverse Voltage	650	V	$T_J = 25^\circ C$
I_F	Continuous Forward Current	20	A	$T_C = 25^\circ C$
		15.5		$T_C = 75^\circ C$
		10		$T_C = 125^\circ C$
I_{FRM}	Repetitive Peak Forward Surge Current	51	A	$T_C = 25^\circ C, T_P = 10ms, \text{Half Sine Wave}$
		46		$T_C = 110^\circ C, T_P = 10ms, \text{Half Sine Wave}$
I_{FSM}	Non-Repetitive Peak Forward Surge Current	67	A	$T_C = 25^\circ C, T_P = 10ms, \text{Half Sine Wave}$
		61		$T_C = 110^\circ C, T_P = 10ms, \text{Half Sine Wave}$
P_D	Power Dissipation	50	W	$T_C = 25^\circ C$
		21.5		$T_C = 110^\circ C$
$T_{J,max}$	Operating Junction Temperature	175	$^\circ C$	
T_{stg}	Storage Temperature Range	-55 to 175	$^\circ C$	

Thermal characteristics

Symbol	Parameter	Min.	Typ.	Max.	Unit
R_{thJC}	Thermal resistance		3.0		$^{\circ}\text{C}/\text{W}$

Electrical Characteristics

Symbol	Parameter	Value			Unit	Test Conditions
		Min.	Typ.	Max.		
V_{DC}	DC Blocking Voltage	650			V	$I_R=100\mu\text{A}, T_J=25^{\circ}\text{C}$
V_F	Forward Voltage		1.35 1.65	1.6 2.0	V	$I_F=10\text{A}, T_J=25^{\circ}\text{C}$ $I_F=10\text{A}, T_J=175^{\circ}\text{C}$
I_R	Reverse Current		2 10	50 200	μA	$V_R=650\text{V}, T_J=25^{\circ}\text{C}$ $V_R=650\text{V}, T_J=175^{\circ}\text{C}$
Q_C	Total Capacitive Charge		38		nC	$I_F=10\text{A}, dI/dt=300\text{A}/\mu\text{s}$ $T_J=25^{\circ}\text{C}, V_R=400\text{V}$
C	Total Capacitance		683 88 82		pF	$V_R=1\text{V}, T_J=25^{\circ}\text{C}, f=1\text{ MHz}$ $V_R=200\text{V}, T_J=25^{\circ}\text{C}, f=1\text{ MHz}$ $V_R=400\text{V}, T_J=25^{\circ}\text{C}, f=1\text{ MHz}$

Typical Performance

Fig. 1 Forward Characteristics

Fig. 2 Reverse Characteristics

Typical Performance

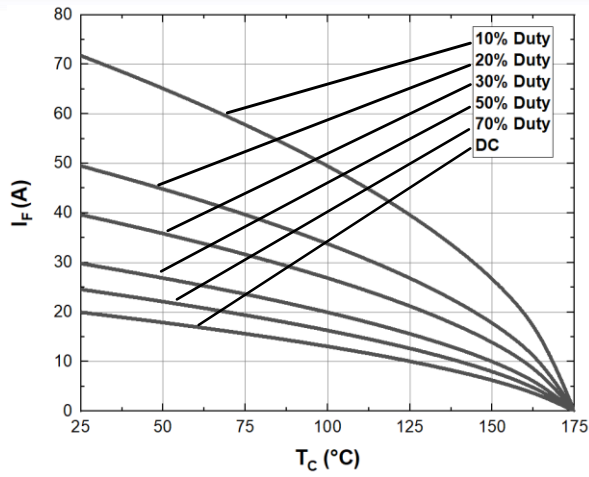


Fig. 3 Current Derating

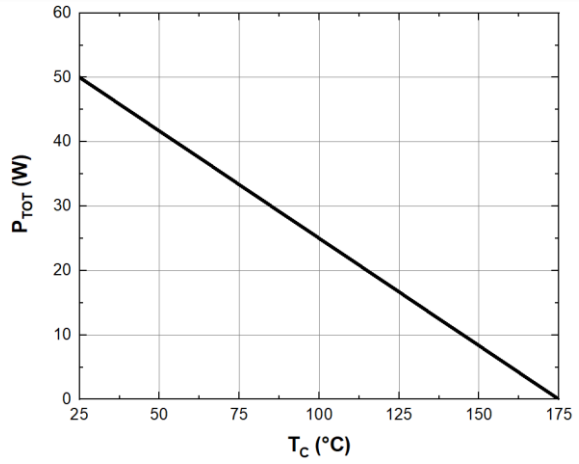


Fig. 4 Power Derating

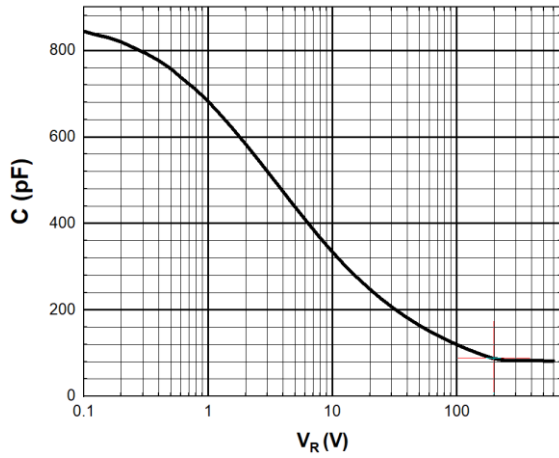


Fig. 5 Capacitance vs. Reverse Voltage

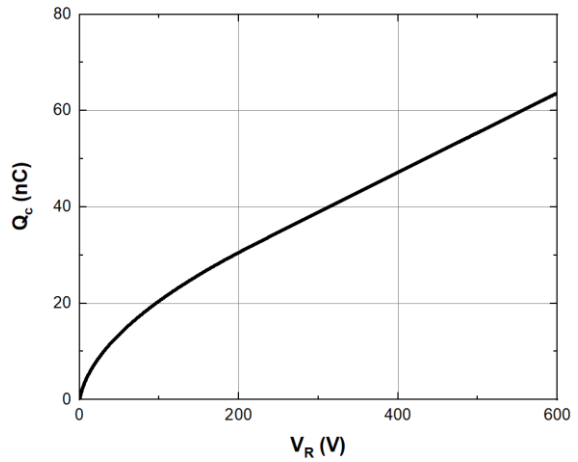


Fig. 6 Recovery Charge vs. Reverse Voltage

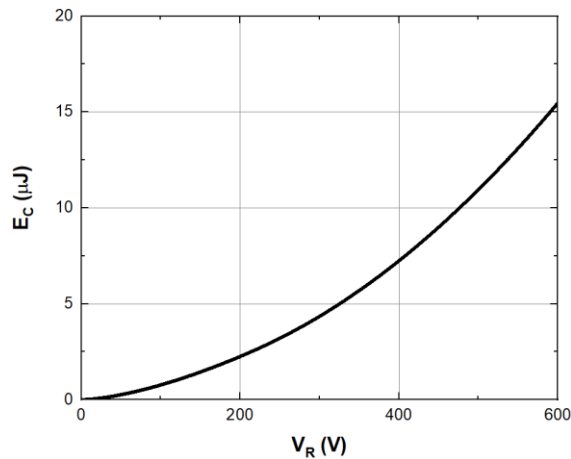
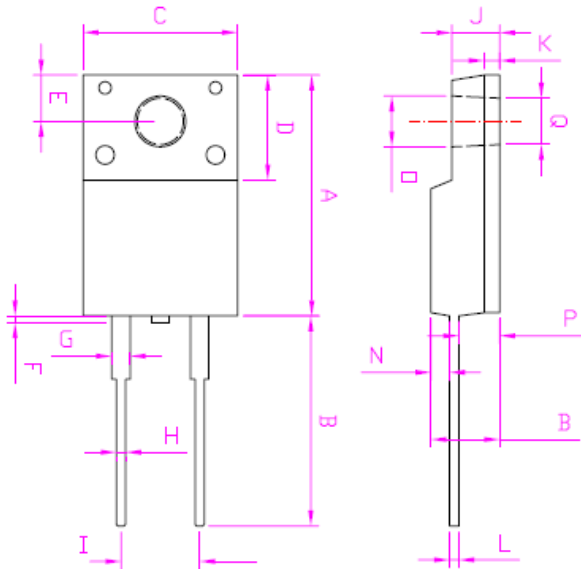


Fig. 7 Capacitance stored Energy

Package TO-220-2L (Unit: mm)



REF.DIM	DATA BOOK mm		
	NOR	MIN	MAX
A	15.6	14.8	16.1
B	13	12.65	13.8
C	10	9.85	10.36
D	6.5	4.6	6.8
E	3.0	2.55	3.5
F			1
G	1.2	1	1.45
H	0.6	0.3	0.9
I	5.1	4.8	5.4
J	3.1	2.34	3.3
K	1.0	0.55	1.3
L	0.6	0.36	0.8
M	4.45	4.2	4.9
N	1.2	1.1	1.8
O	3.3	2.9	3.5
P	2.6	2.5	3.15
Q	3	2.9	3.5

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